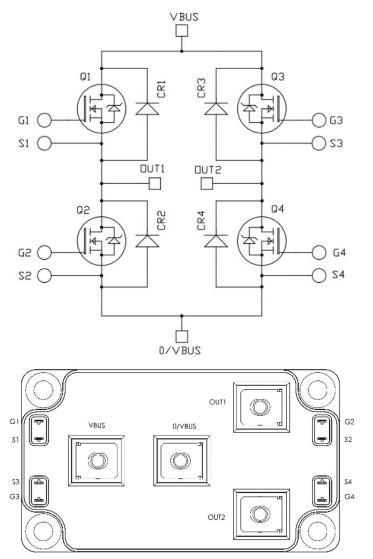


Full Bridge SiC Power Module

Product Overview

The MSCSM170HM087CAG device is a 1700 V/238 A full bridge silicon carbide (SiC) power module.



All ratings at T_J = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM170HM087CAG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF
- Kelvin source for easy drive
- Low stray inductance
- M5 power connectors
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM170HM087CAG device:

- High efficiency converter
- Outstanding performance at high-frequency operation
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

Applications

The following are the applications of MSCSM170HM087CAG device:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

The following sections show the electrical specifications of the MSCSM170HM087CAG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings (per SiC MOSFET) of the MSCSM170HM087CAG device.

Table 1-1. Absolute Maximum Ratings

| Symbol | Parameter | | Maximum Ratings | Unit |
|---------------------|---|------------------------|-----------------|------|
| V _{DSS} | Drain-Source voltage | | 1700 | V |
| I _D | Continuous drain current $T_C = 25 \ ^{\circ}C$ | | 238 | A |
| | | T _C = 80 °C | 189 | |
| I _{DM} | Pulsed drain current | | 480 | |
| V _{GS} | Gate-Source voltage | | -10/23 | V |
| R _{DS(on)} | Drain-Source ON resistance | | 11.3 | mΩ |
| PD | Power dissipation | T _C = 25 °C | 1114 | W |

The following table lists the electrical characteristics (per SiC MOSFET) of the MSCSM170HM087CAG device.

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|---------------------|------------------------------------|---|-------------------------|-----|------|------|------|
| I _{DSS} | Zero gate voltage drain current | V _{GS} = 0 V; V _{DS} = 1700 V | | _ | 40 | 400 | μA |
| R _{DS(on)} | Drain-Source on | V _{GS} = 20 V | T _J = 25 °C | | 8.8 | 11.3 | mΩ |
| | resistance | I _D = 120 A | T _J = 175 °C | | 15.4 | | |
| V _{GS(th)} | Gate threshold voltage | $V_{GS} = V_{DS}; I_D = 10 \text{ mA}$ | | 1.8 | 3.2 | | V |
| I _{GSS} | Gate-Source leakage current | V_{GS} = 20 V; V_{DS} = 0 V | | _ | _ | 400 | nA |

Table 1-2. Electrical Characteristics

Electrical Specifications

The following table lists the dynamic characteristics (per SiC MOSFET) of the MSCSM170HM087CAG device.

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|---------------------|------------------------------|---|-------------------------|-----|-------|-------|------|
| C _{iss} | Input capacitance | V _{GS} = 0 V | | — | 13200 | — | pF |
| C _{oss} | Output capacitance | V _{DS} = 1000 V | | — | 600 | — | |
| C _{rss} | Reverse transfer capacitance | f = 1 MHz | | - | 40 | _ | |
| Qg | Total gate charge | V_{GS} = -5 V/20 V | | - | 712 | _ | nC |
| Q _{gs} | Gate-source charge | V _{Bus} = 850 Vz | | - | 196 | — | |
| Q _{gd} | Gate-drain charge | I _D = 120 A | | - | 108 | _ | |
| T _{d(on)} | Turn-on delay time | V_{GS} = -5 V/20 V | | _ | 75 | — | ns |
| Tr | Rise time | V _{Bus} = 900 V | | — | 75 | | |
| T _{d(off)} | Turn-off delay time | $I_{D} = 200 \text{ A}$ $T_{J} = 150 \text{ °C}$ $R_{GON} = 7 \Omega$ $R_{GOFF} = 4 \Omega$ | | _ | 153 | _ | |
| T _f | Fall time | | | | 56 | — | |
| Eon | Turn-on energy | V _{GS} = -5 V/20 V | T _J = 150 °C | _ | 9 | _ | mJ |
| E _{off} | Turn-off energy | V _{Bus} = 900 V I _D = 200 A R _{GON} = 7 Ω R _{GOFF} = 4 Ω | T _J = 150 °C | | 4.8 | _ | |
| R _{Gint} | Internal gate resistance | 9 | | _ | 1.46 | _ | Ω |
| R _{thJC} | Junction-to-case therm | al resistance | | — | — | 0.135 | °C/W |

Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics (per SiC MOSFET) of the MSCSM170HM087CAG device.

Table 1-4. Body Diode Ratings and Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit |
|-----------------|--------------------------|---|-----|------|-----|------|
| V_{SD} | Diode forward voltage | V_{GS} = 0 V; I _{SD} = 120 A | | 3.7 | — | V |
| | | V_{GS} = -5 V; I _{SD} = 120 A | — | 3.9 | — | |
| t _{rr} | Reverse recovery time | I _{SD} = 120 A | | 27 | _ | ns |
| Q _{rr} | Reverse recovery charge | V_{GS} = -5 V | | 2600 | — | nC |
| Irr | Reverse recovery current | V _R = 900 V di _F /dt = 4000 A/µs | | 184 | _ | A |

1.2 SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC Schottky diode ratings and characteristics of the MSCSM170HM087CAG device.

Table 1-5. SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|-------------------|------------------------------|-------------------------------|-------------------------|-----|-----|-------|------|
| V _{RRM} | Peak repetitive reverse volt | age | | _ | — | 1700 | V |
| I _{RRM} | Reverse leakage current | V _R = 1700 V | T _J = 25 °C | _ | 40 | 800 | μA |
| | | | T _J = 175 °C | | 600 | — | |
| I _F | DC forward current | — | T _C = 125 °C | _ | 120 | — | A |
| V _F | Diode forward voltage | I _F = 120 A | T _J = 25 °C | _ | 1.5 | 1.8 | V |
| | | | T _J = 175 °C | _ | 2.3 | — | |
| Q _C | Total capacitive charge | V _R = 900 V | | | 920 | — | nC |
| С | Total capacitance | f = 1 MHz, V _R = 6 | 00 V | _ | 668 | — | pF |
| | | f = 1 MHz, V _R = 9 | 00 V | | 552 | — | |
| R _{thJC} | Junction-to-case thermal re | sistance | | _ | _ | 0.149 | °C/W |

1.3 Thermal and Package Characteristics

The following table lists the package characteristics of the MSCSM170HM087CAG device.

Table 1-6. Thermal and Package Characteristics

| Symbol | Characteristic | Min | Max | Unit | | |
|-------------------|---|---|------------|------|-----------------------|-----|
| V _{ISOL} | RMS isolation voltage, any terminal to ca | se t = 1 min, 5 | 0 Hz/60 Hz | 4000 | — | V |
| TJ | Operating junction temperature range | | | -40 | 175 | °C |
| T _{JOP} | Recommended junction temperature und | Recommended junction temperature under switching conditions | | | T _{Jmax} –25 | |
| T _{STG} | Storage case temperature | | | | 125 | |
| T _C | Operating case temperature | | | -40 | 125 | |
| Torque | Mounting torque | To heatsink | M6 | 3 | 5 | N.m |
| | | For terminals | M5 | 2 | 3.5 | |
| Wt | Package weight | | | — | 300 | g |

Electrical Specifications

1.4 Typical SiC MOSFET Performance Curve

The following figures show the SiC MOSFET performance curves of the MSCSM170HM087CAG device.

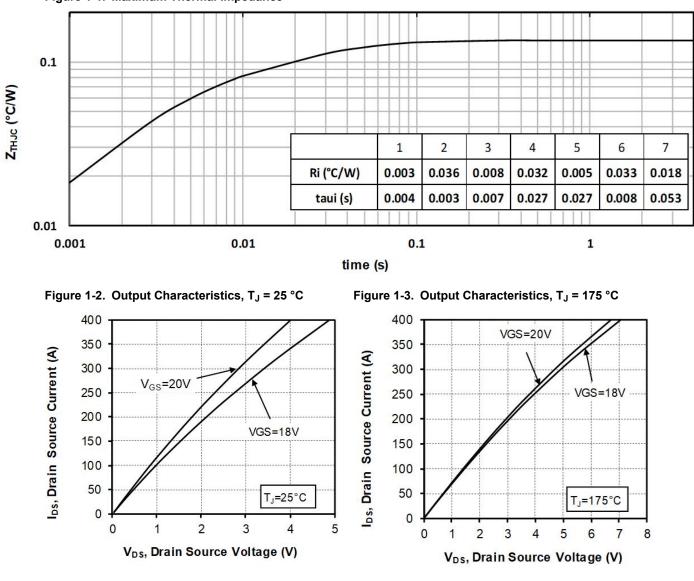


Figure 1-1. Maximum Thermal Impedance

Electrical Specifications

12

14

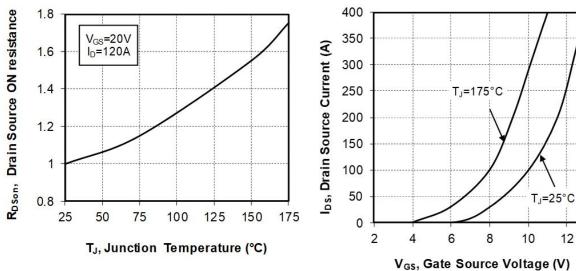
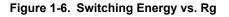




Figure 1-4. Normalized R_{DS(on)} vs. Temperature



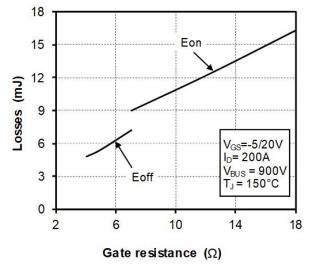
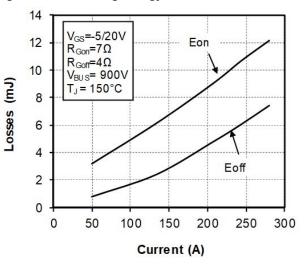


Figure 1-7. Switching Energy vs. Current

Figure 1-5. Transfer Characteristics



Electrical Specifications

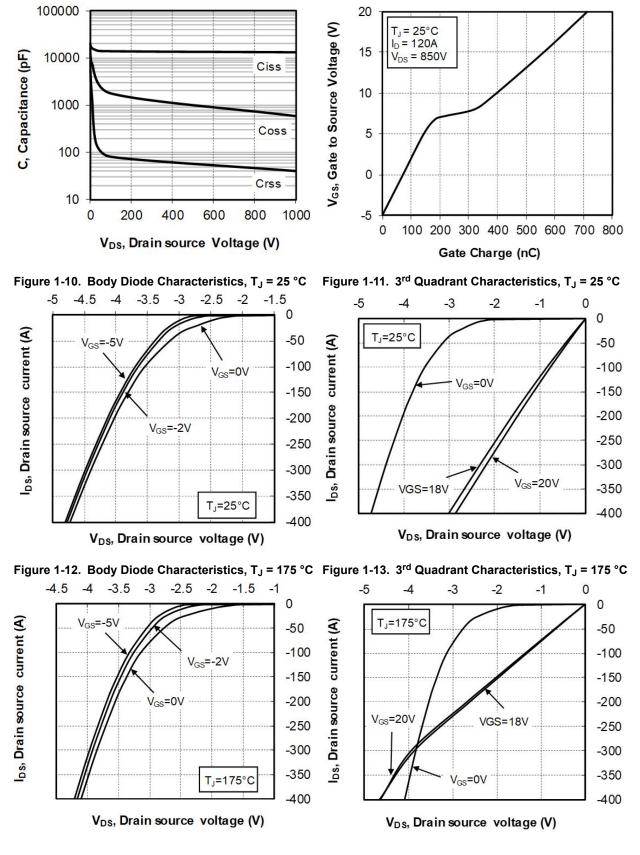


Figure 1-8. Capacitance vs. Drain Source Voltage

Figure 1-9. Gate Charge vs. Gate Source Voltage

Electrical Specifications

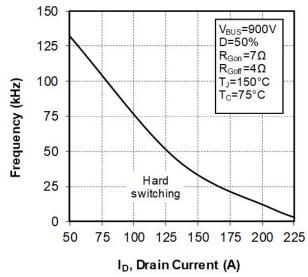


Figure 1-14. Operating Frequency vs. Drain Current

Electrical Specifications

1.5 Typical SiC Diode Performance Curve

The following figures show the SiC diode performance curves of the MSCSM170HM087CAG device.

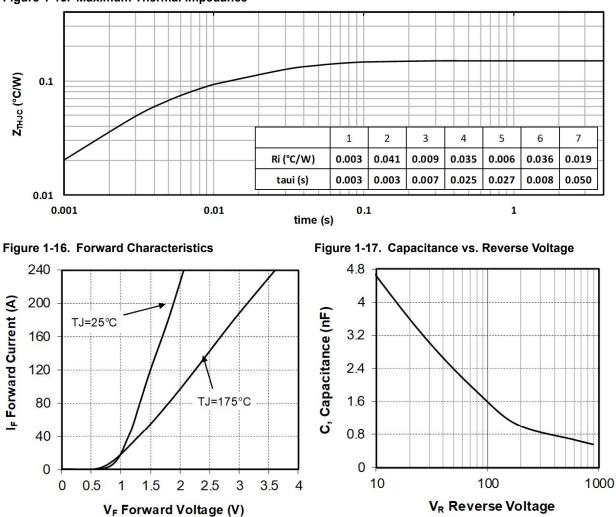


Figure 1-15. Maximum Thermal Impedance

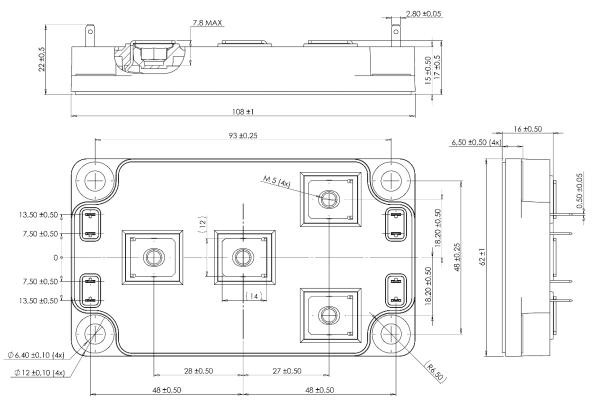
2. Package Specifications

The following section shows the package specification of the MSCSM170HM087CAG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM170HM087CAG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See application note APT0601—Mounting Instructions for SP6 Power Modules.

3. Revision History

| Revision | Date | Description |
|----------|---------|---|
| А | 05/2021 | This is the first publication of this document. |

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